1N4148WS

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Vishay Semiconductors

Small Signal Fast Switching Diode

MARKING (example only)



Bar = cathode marking XY = type code

DESIGN SUPPORT TOOLS click logo to get started



FEATURES

- Silicon epitaxial planar diode
- Fast switching diodes
- AEC-Q101 qualified available
- Base P/N-E3 RoHS-compliant, commercial grade
- Base P/N-HE3 RoHS-compliant, AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

MECHANICAL DATA

Case: SOD-323 Weight: approx. 4.3 mg Packaging codes / options: 18/10K per 13" reel (8 mm tape), 10K/box 08/3K per 7" reel (8 mm tape), 15K/box

| PARTS TABLE | | | | |
|-------------|------------------------------------|-----------------------|--------------|---------------|
| PART | ORDERING CODE | CIRCUIT CONFIGURATION | TYPE MARKING | REMARKS |
| 1N4148WS | 1N4148WS-E3-08 or 1N4148WS-E3-18 | Single | A2 | Tape and reel |
| | 1N4148WS-HE3-08 or 1N4148WS-HE3-18 | Single | AZ | |

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|--|---------------------------|--------------------|-------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Reverse voltage | | V _R | 75 | N/ | |
| Repetitive peak reverse voltage | | V _{RRM} | 100 | V | |
| Average rectified current half wave rectification with resistive load ⁽¹⁾ | f ≥ 50 Hz | I _{F(AV)} | 150 | mA | |
| Surge forward current | $t < 1 s and T_j = 25 °C$ | I _{FSM} | 350 | | |
| Power dissipation (1) | | P _{tot} | 200 | mW | |

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature.

| THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|---|----------------|-------------------|-------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Thermal resistance junction to ambient air (1) | | R _{thJA} | 650 | K/W | |
| Junction temperature | | Tj | 150 | °C | |
| Storage temperature range | | T _{stg} | -65 to +150 | °C | |
| Operating temperature range | | T _{op} | -55 to +150 | °C | |

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature

Rev. 2.3, 06-Jul-17

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RoHS

COMPLIANT

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| ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|--|--|-----------------|------|------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Forward voltage | I _F = 10 mA | VF | | | 1 | V |
| Forward voltage | I _F = 100 mA | V _F | | | 1.2 | V |
| | V _R = 20 V | I _R | | | 25 | nA |
| Leakage current | V _R = 75 V | I _R | | | 5 | μΑ |
| Leakage current | V _R = 100 V | I _R | | | 100 | |
| | $V_{R} = 20 \text{ V}, \text{ T}_{j} = 150 ^{\circ}\text{C}$ | I _R | | | 50 | |
| Diode capacitance | $V_F = V_R = 0 V$ | CD | | | 4 | pF |
| Voltage rise when switching ON | Tested with 50 mA pulses, $t_p = 0.1 \ \mu s$, rise time < 30 ns, $f_p = (5 \text{ to } 100) \text{ kHz}$ | V _{fr} | | | 2.5 | V |
| Reverse recovery time | $I_F = 10 \text{ mA}, i_R = 1 \text{ mA}, V_R = 6 \text{ V}, \\ R_L = 100 \ \Omega$ | t _{rr} | | | 4 | ns |

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

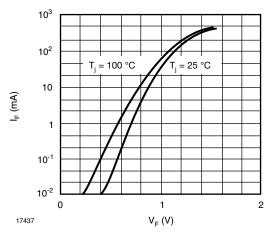


Fig. 1 - Forward Characteristics

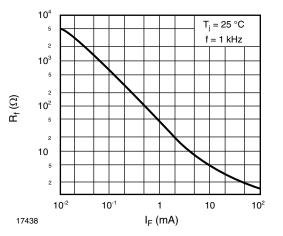


Fig. 2 - Dynamic Forward Resistance vs. Forward Current

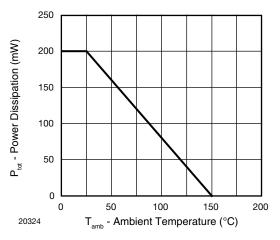


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

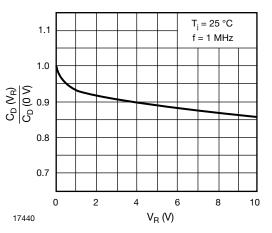


Fig. 4 - Relative Capacitance vs. Reverse Voltage

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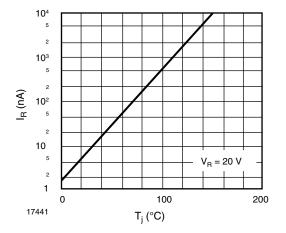


Fig. 5 - Leakage Current vs. Junction Temperature

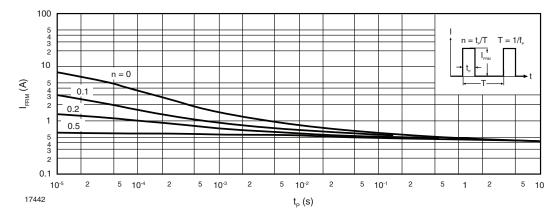
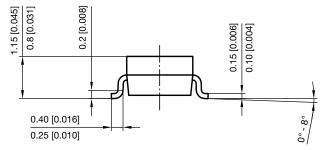


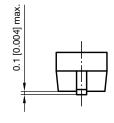
Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration

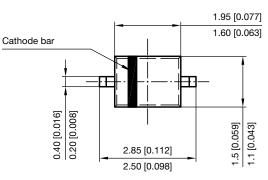
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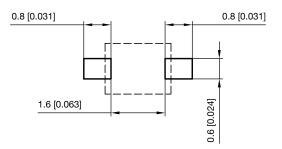
PACKAGE DIMENSIONS in millimeters (inches): SOD-323







Footprint recommendation:



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